



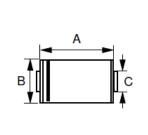
# LITE-ON SEMICONDUCTOR ES3G(LS)

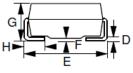
#### SURFACE MOUNT **REVERSE VOLTAGE – 400 Volts** SUPER FAST RECTIFIERS FORWARD CURRENT – 3.0 Ampere **FEATURES** SMC · Glass passivated chip · Super fast switching for high efficiency

- · For surface mounted applications
- · Low forward voltage drop and high current capability
- · Low reverse leakage current
- Available in "Green" Package: SMC
  - Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
  - Halogen and Antimony Free. "Green" Device (Note 3)

### **MECHANICAL DATA**

- · Case: Molded plastic
- · Case Material: Molding compound, UL Flammability classification 94V-0,"Halogen-free".
- · Polarity: Color band denotes cathode
- Weight: 0.021 grams





SMC				
DIM	MIN MAX			
А	6.60	7.11		
В	5.59	6.22		
С	2.92	3.18		
D	0.15	0.31		
Е	7.75	8.13		
F	0.05	0.20		
G	2.01	2.50		
Н	0.76	1.52		
All dimension in millimeter				

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

PARAMETER		SYMBOL	ES3G	UNIT
Maximum Repetitive Peak Reverse Voltage		V <sub>RRM</sub>	400	V
Maximum RMS Voltage		V <sub>RMS</sub>	280	V
Maximum DC Blocking Voltage		V <sub>DC</sub>	400	V
Maximum Average Forward Rectified Current	@T <sub>L</sub> =110°C	I <sub>(AV)</sub>	3.0	А
Peak Forward Surge Current 8.3ms single half sine-wave super imposed on rated load (JEDEC METHOD)		I <sub>FSM</sub>	100	А
Peak Forward Surge Current 1ms single half sine-wave	@ T <sub>J</sub> =25°C	I <sub>FSM</sub>	200	А
$^{2}$ t Rating for fusing (3ms $\leq$ t $\leq$ 8.3ms)		l <sup>2</sup> t	41.5	A <sup>2</sup> S
Maximum forward Voltage at 3.0A DC		VF	1.25	V
Maximum DC Reverse Current at Rated DC Blocking Voltage	@ T」=25°C @ T」=125°C	I <sub>R</sub>	10 500	uA
Maximum Reverse Recovery Time (Note 4)		t <sub>rr</sub>	25 20 (Typ.)	ns
Typical Junction Capacitance (Note 5)		Ст	45	pF
Typical Thermal Resistance (Note 6)		R <sub>thJL</sub>	10	*CAM
		R <sub>thJA</sub>	50	•C/W
Operating Temperature Range		TJ	-55 to + 150	°C
Storage Temperature Range		T <sub>STG</sub>	-55 to + 150	°C

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony

compounds.

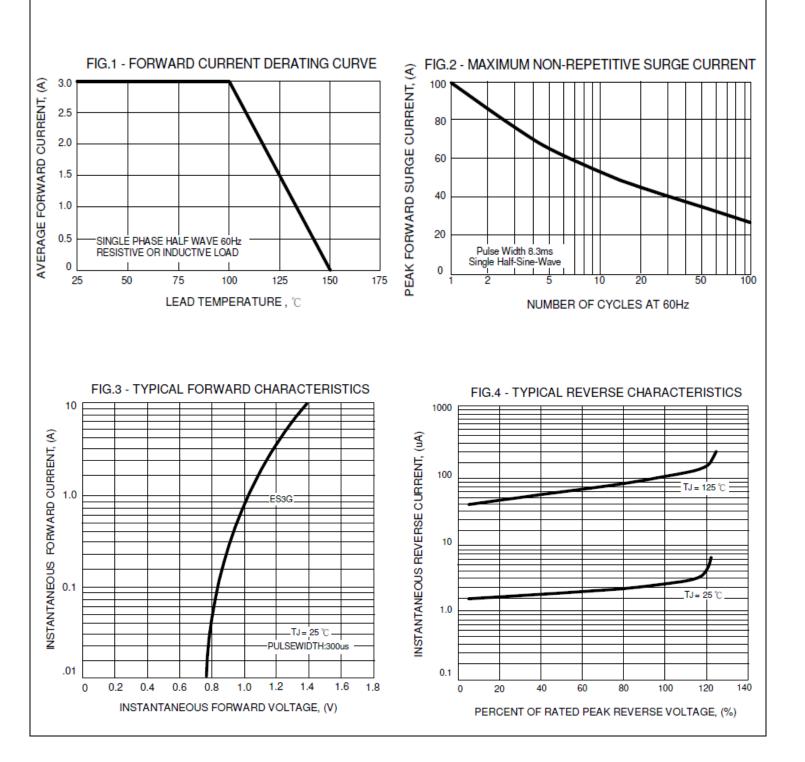
4. Reverse Recovery Test Conditions :I<sub>F</sub>=0.5A,I<sub>R</sub>=1.0A,I<sub>rr</sub>=0.25A.

5. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

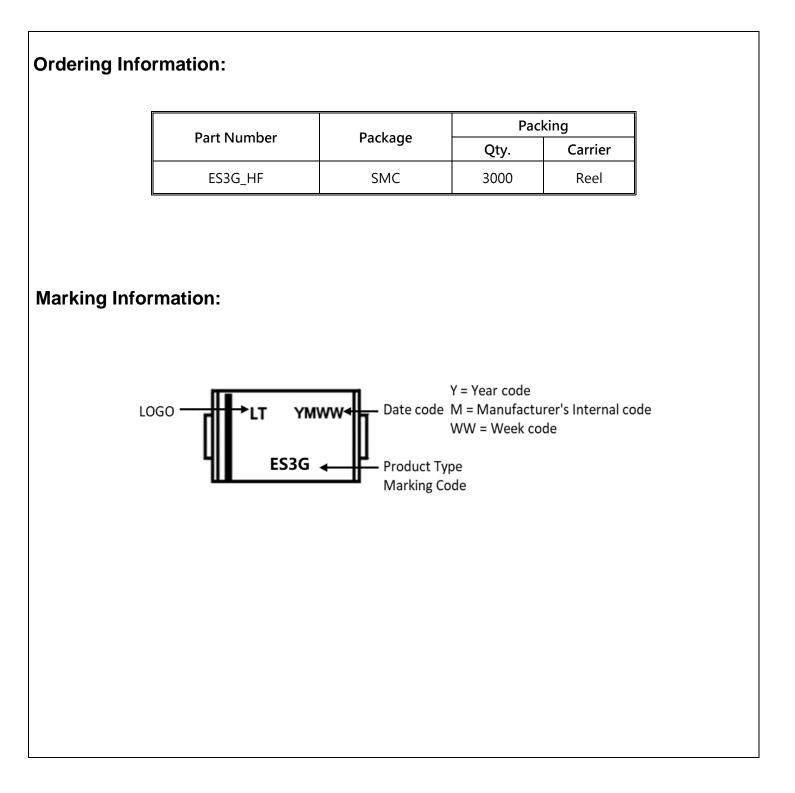
6. Thermal Resistance junction to Lead and Ambient.



### LITE-ON SEMICONDUCTOR









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